

Pseudogap Phase Boundary in Overdoped $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ Studied by Measuring Out-of-plane Resistivity under the Magnetic Fields

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Abstract

In order to elucidate the relationship between the pseudogap and high- T_c superconductivity, the characteristic pseudogap temperature T^* in $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ system has been systematically evaluated as a function of doping, especially focusing on its overdoped region, by measuring the out-of-plane resistivity ρ_c . Overdoped samples have been prepared by annealing TSFZ-grown $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystals under the high oxygen pressures (990 kgf/cm²). At a zero field, the ρ_c showed a metallic behavior down to T_c (= 62 K), while under the magnetic fields of over 3 T, ρ_c showed typical upturn behavior from around 65 K upon decreasing temperature. This result suggests that the pseudogap and superconductivity are different phenomena.

Keywords: Pseudogap, $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$, Magnetoresistance, Out-of-plane resistivity, Superconductive fluctuation

1. Introduction

It is well recognized that an understanding of the pseudogap phenomena in high- T_c cuprates is crucially important to understand the mechanism of high- T_c superconductivity. It has not been yet clarified, however, whether it is a precursor of high- T_c superconductivity or it is some kind of a competing order against the superconductivity. In the former case, the pseudogap temperature T^* may decrease with increasing doping and merge with T_c in the overdoped state. In the latter case, the T^* may cross the T_c dome and point to zero at the quantum critical point. Thus, in order to clarify the origin of the pseudogap, it is important to investigate the T^* as a function of doping. Experimental data in the heavily overdoped state is lacking, however, especially on $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (Bi-2212) due to the difficulty in sample preparations.

Among various techniques to detect the pseudogap effect, the out-of-plane resistivity ρ_c is one of the most powerful method, since it directly probes the electronic density of states (DOS) around the Fermi level. Then, the ρ_c shows a typical upturn below the pseudogap temperature T^* [1]. Recently, the ρ_c of Bi-2212 has also been measured under the high magnetic fields up to 60 T and a negative magnetoresistance has been observed below the T^* [2]. This result has been attributed to the suppression of the pseudogap effect under the high magnetic fields.

In this paper, we extended the doping level of Bi-2212 to the heavily overdoped state and measured the out-of-plane resistivity ρ_c under the various magnetic fields. Based on the results, we discuss the pseudogap phase boundary in the overdoped Bi-2212.

2. Experimental

Single crystals were grown using the traveling solvent floating zone method [3]. Heavily overdoped samples with T_c (= 62 K) were made by high O_2 pressure (990 kgf/cm²) annealing at 500 °C for 100 h. The c-axis length was estimated from the X-ray diffraction pattern using fitting method of Nelson-Riley function. The c-axis length of the annealed sample shrunk about 0.15 Å compared with that of the as-grown sample, confirming that excess oxygen was actually incorporated into the sample [4]. The doping level p was estimated as 0.22 using the empirical relation proposed by J. L. Tallon [5]. ρ_c measurements were carried out by a DC four-terminal method. Magnetic fields were applied up to 17.5 T parallel to the c-axis by a superconducting magnet.

3. Results and Discussion

Figure 1 shows the temperature dependence of out-of-plane resistivity ρ_c for an optimally doped Bi-2212 single crystal under various magnetic fields. At a zero field, the ρ_c is semiconductive in all temperature regions measured. The T^* can safely be estimated as around room temperature. When we applied magnetic fields, we observed negative magnetoresistance at low temperatures near T_c . The inset of Fig. 1 shows the enlarged ρ_c just above T_c . The data at the magnetic field of 17.5 T deviates downward from that at a zero field below around 120 K, indicating the occurrence of the negative magnetoresistance.

Although the typical upturn of the ρ_c is generally thought to be caused by the opening of the pseudogap [1], this behav-

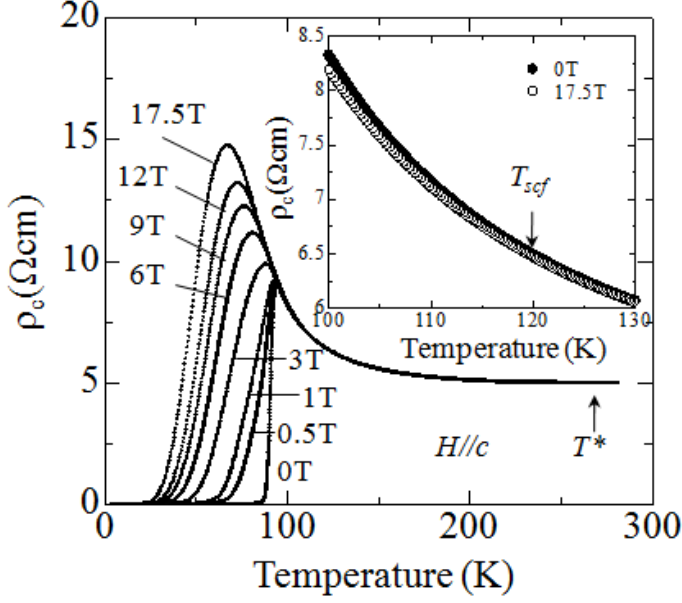


Figure 1: Out-of-plane resistivity ρ_c , of an $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystal under the various magnetic fields. The inset shows the expanded plots of the out-of-plane resistivity ρ_c just above T_c .

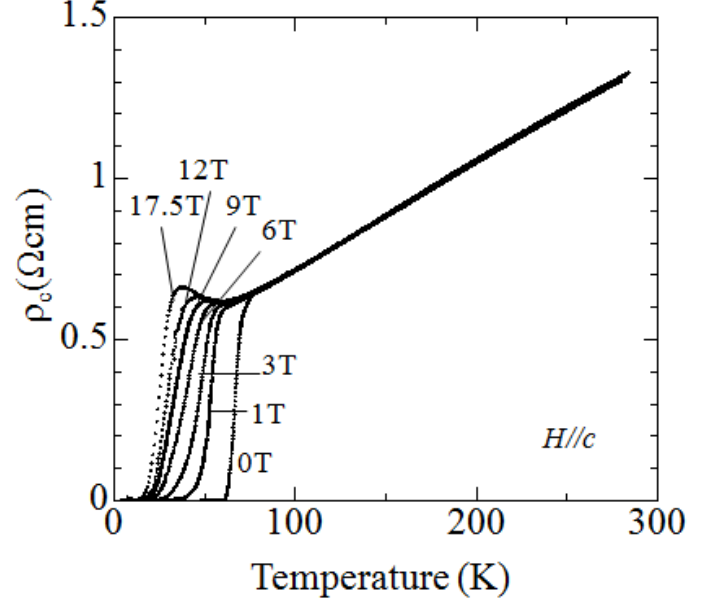


Figure 2: Out-of-plane resistivity ρ_c , of an heavily overdoped $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ single crystal under the various magnetic fields.

ior can also be caused by the superconductive fluctuation effect [6], if the material has an electronically extreme 2D nature such as high- T_c cuprates. This is because the in-plane DOS reduction by the superconductive fluctuation affects the ρ_c in a similar manner as that by the pseudogap. Then, when the superconductivity is suppressed by the magnetic fields, the DOS is expected to be recovered and cause the negative magnetoresistance. Consequently, the estimated temperature, 120 K, for the negative magnetoresistance may be the onset temperature, T_{scf} , for the superconductive fluctuation. Indeed, the temperature coincides with that estimated by the measurements of static susceptibilities [1]. The observed sharp increase in ρ_c near T_c may be attributed to both the pseudogap and the superconductive fluctuation effects.

Figure 2 shows the temperature dependence of out-of-plane resistivity ρ_c for the annealed sample under various magnetic fields. At a zero field, the ρ_c showed a metallic behavior down to $T_c (= 62 \text{ K})$, indicating the sample is in a heavily overdoped state, while under the magnetic fields of over 3 T, the ρ_c showed typical upturn behavior from around 65 K upon decreasing temperature. This implies that the pseudogap temperature T^* ($= 65 \text{ K}$) which has been hidden by onset of superconductivity at a zero field has emerged along with the suppression of superconductivity by the application of the high magnetic fields. On the other hand, T_{scf} could not be found for this sample. If the T_{scf} scales with T_c , the T_{scf} may be higher than observed T^* . This is probably because the electronic 2D nature, which is necessary to observe the upturn of ρ_c due to the superconductive fluctuation effect, become weak in the heavily overdoped state. This result suggests that the T^* crosses the T_c dome in the heavily overdoped Bi-2212.

4. Conclusion

In order to understand the pseudogap phenomena more in detail, the pseudogap temperatures T^* of the Bi-2212 single crystals have been investigated by the measurements of the out-of-plane resistivity ρ_c under the magnetic field of up to 17.5 T. The results of an optimally doped sample indicate that, although the typical upturn in ρ_c first occurs at T^* due to the opening of the pseudogap, the superconductive fluctuation effect is added to the behavior at temperatures near T_c . Moreover, the results of the heavily overdoped sample indicate that the T^* seem to cross the T_c dome. Both these results suggest that the pseudogap and superconductivity are different phenomena.

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